# NSN 5961-00-554-8213

Transistor - Page 1 of 2



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Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# Terminal Length:

0.480 inches

# **Overall Height:**

0.300 inches

## **Overall Width:**

1.050 inches

# Mounting Facility Quantity:

2

## Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

# **Mounting Method:**

Terminal and unthreaded hole

## **Terminal Circle Diameter:**

0.440 inches

# **Features Provided:**

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 7.0 emitter to base voltage, static, collector open and 120.0 breakdown voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

50.00 amperes source cutoff current and 10.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

80.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 uninsulated wire lead and 2 unthreaded hole

## Shelf Life:

N/a

## Unit Of Measure:

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- Demilitarization:
- Yes demil/mli

# **NSN 5961-00-554-8213** Transistor - Page 2 of 2

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